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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







74AHC240; 74AHCT240

Octal buffer/line driver; inverting; 3-state
Rev. 4 — 25 September 2013

Product data sheet

1. **General description**

The 74AHC240 and 74AHCT240 are 8-bit inverting buffer/line drivers with 3-state outputs. These devices can be used as two 4-bit buffers or one 8-bit buffer. They feature two output enables (1OE and 2OE), each controlling four of the 3-state outputs. A HIGH on nOE causes the outputs to assume a high-impedance OFF-state. Inputs are over voltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

2. **Features and benefits**

- Balanced propagation delays
- All inputs have a Schmitt-trigger action
- Inputs accepts voltages higher than V_{CC}
- For 74AHC240 only: operates with CMOS input levels
- For 74AHCT240 only: operates with TTL input levels
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - CDM JESD22-C101D exceeds 1000 V
- Multiple package options
- Specified from −40 °C to +85 °C and from −40 °C to +125 °C

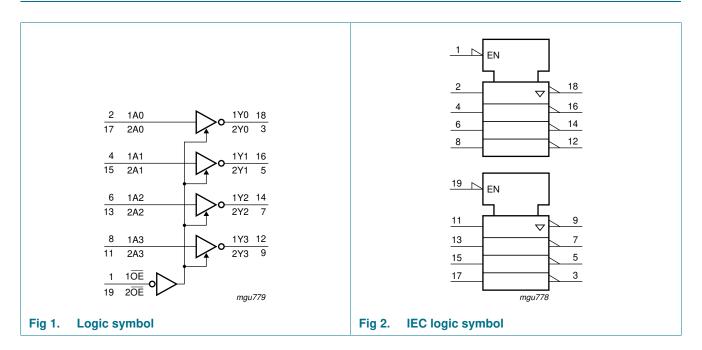
3. Ordering information

Table 1. **Ordering information**

Type number	Package							
	Temperature range	Name	Description	Version				
74AHC240D	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1				
74AHCT240D			body width 7.5 mm					
74AHC240PW	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads;	SOT360-1				
74AHCT240PW			body width 4.4 mm					
74AHC240BQ	-40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced	SOT764-1				
74AHCT240BQ	very thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm							

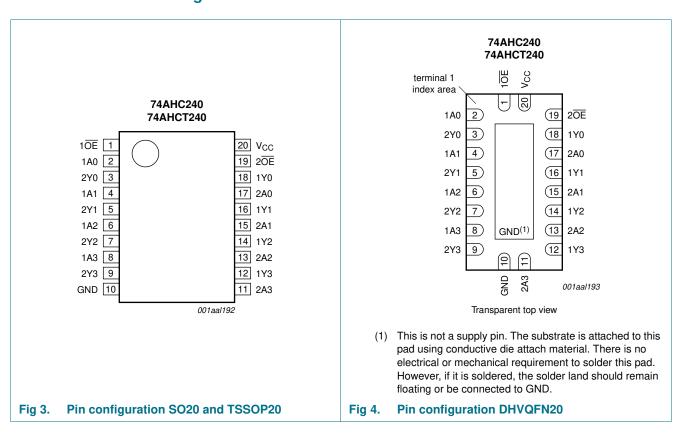


4. Functional diagram



5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1 OE	1	output enable input (active LOW)
2 OE	19	output enable input (active LOW)
1A0, 1A1, 1A2, 1A3	2, 4, 6, 8	data input
2A0, 2A1, 2A2, 2A3	17, 15, 13, 11	data input
1Y0, 1Y1, 1Y2, 1Y3	18, 16, 14, 12	data output
2Y0, 2Y1, 2Y2, 2Y3	3, 5, 7, 9	data output
GND	10	ground (0 V)
V _{CC}	20	power supply

6. Functional description

Table 3. Function table[1]

Control nOE	Input	Output
nOE	nAn	nYn
L	L	Н
L	Н	L
Н	X	Z

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

		<i>y</i> , , , , , , , , , , , , , , , , , , ,		10	,
Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7.0	V
V_{I}	input voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 V$	<u>[1]</u> –20	-	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I _{CC}	supply current		-	75	mA
I _{GND}	ground current		-75	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[2] -	500	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For SO20 package: above 70 °C the value of P_{tot} derates linearly with 8.0 mW/K. For TSSOP20 package: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K. For DHVQFN20 package: above 60 °C the value of P_{tot} derates linearly with 4.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74AHC24	0					
V_{CC}	supply voltage		2.0	5.0	5.5	V
V _I	input voltage		0	-	5.5	V
V _O	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V_{CC} = 3.3 V \pm 0.3 V	-	-	100	ns/V
		V_{CC} = 5 V \pm 0.5 V	-	-	20	ns/V
74AHCT2	240					
V_{CC}	supply voltage		4.5	5.0	5.5	V
V_{I}	input voltage		0	-	5.5	V
Vo	output voltage		0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 5 V \pm 0.5 V$	-	-	20	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC2	40				•	'				
V_{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	-	-	1.5	-	1.5	-	٧
	input voltage	V _{CC} = 3.0 V	2.1	-	-	2.1	-	2.1	-	٧
		V _{CC} = 5.5 V	3.85	-	-	3.85	-	3.85	-	٧
V _{IL}	LOW-level	$V_{CC} = 2.0 \text{ V}$	-	-	0.5	-	0.5	-	0.5	٧
	input voltage	V _{CC} = 3.0 V	-	-	0.9	-	0.9	-	0.9	٧
		V _{CC} = 5.5 V	-	-	1.65	-	1.65	-	1.65	٧
011	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}								
		$I_O = -50 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	٧
		$I_O = -50 \mu A; V_{CC} = 3.0 V$	2.9	3.0	-	2.9	-	2.9	-	٧
		$I_O = -50 \mu A$; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	٧
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	٧
		$I_{O} = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.80	-	3.70	-	٧
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 50 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 50 \mu A; V_{CC} = 3.0 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 50 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	٧
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	٧
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	٧

74AHC_AHCT240

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 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C	to +85 °C	–40 °C t	Unit	
			Min	Тур	Max	Min	Max	Min	Max	
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	μΑ
l _{OZ}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.25	-	±2.5	-	±10.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μΑ
Cı	input capacitance	$V_I = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
C _O	output capacitance		-	4	-	-	-	-	-	pF
74AHCT	240									
V_{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	2.0	-	2.0	-	V
V_{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	8.0	-	8.0	-	0.8	V
V_{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = -50 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_0 = -8.0 \text{ mA}$	3.94	-	-	3.80	-	3.70	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 50 \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 8.0 \text{ mA}$	-	-	0.36	-	0.44	-	0.55	V
II	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	-	-	0.1	-	1.0	-	2.0	μА
l _{OZ}	OFF-state output current	$\begin{split} &V_{I}=V_{IH} \text{ or } V_{IL};\\ &V_{O}=V_{CC} \text{ or GND per input}\\ &\text{pin; other inputs at}\\ &V_{CC} \text{ or GND; } I_{O}=0 \text{ A;}\\ &V_{CC}=5.5 \text{ V} \end{split}$	-	-	±0.25	-	±2.5	-	±10.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	4.0	-	40	-	80	μΑ
Δl _{CC}	additional supply current	per input pin; $\begin{aligned} &V_I = V_{CC} - 2.1 \text{ V;} \\ &\text{other pins at } V_{CC} \text{ or GND;} \\ &I_O = 0 \text{ A; } V_{CC} = 4.5 \text{ V to } 5.5 \text{ V} \end{aligned}$	-	-	1.35	-	1.5	-	1.5	mA
C _I	input capacitance	$V_I = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
Co	output capacitance		-	4	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions			25 °C		-4	0 °C to +	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
74AHC2	40				1	'		1		
t _{pd}	propagation delay	nAn to nYn; see Figure 5	[2]							
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V; } C_L = 15 \text{ pF}$		-	3.9	7.5	1.0	8.6	10.8	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; C_L = 50 \text{ pF}$		-	5.8	11.0	1.0	12.5	15.6	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 15 \text{ pF}$		-	2.8	4.8	1.0	5.7	7.1	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 50 \text{ pF}$		-	4.2	7.3	1.0	8.5	10.6	ns
t _{en}	enable time	nOE to nYn; see Figure 6	[2]							
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; C_L = 15 \text{ pF}$		-	4.4	10.0	1.0	12.0	19.4	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; C_L = 50 \text{ pF}$		-	5.8	13.5	1.0	15.5	19.4	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 15 \text{ pF}$		-	3.1	6.5	1.0	7.7	12.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 50 \text{ pF}$		-	4.1	8.5	1.0	10.0	12.5	ns
t _{dis}	disable time	nOE to nYn; see Figure 6	[2]							
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; C_L = 15 \text{ pF}$		-	5.3	9.0	1.0	10.0	18.1	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}; C_L = 50 \text{ pF}$		-	8.9	13.0	1.0	14.5	18.1	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 15 \text{ pF}$		-	3.9	5.8	1.0	6.5	8.1	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V; } C_L = 50 \text{ pF}$		-	6.2	8.7	1.0	9.5	11.8	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}; C_L = 50 \text{ pF};$ $f_i = 1 \text{ MHz}$	[3]	-	9	-	-	-	-	pF

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7.

Symbol	Parameter	Conditions			25 °C		-40	0 °C to +	125 °C	Unit
				Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
74AHCT	240									
t _{pd}	propagation delay	nAn to nYn; see Figure 5	[2]							
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 15 \text{ pF}$		-	3.0	5.8	1.0	6.8	8.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 50 \text{ pF}$		-	4.4	8.4	1.0	9.5	11.9	ns
t _{en}	enable time	nOE to nYn; see Figure 6	[2]							
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 15 \text{ pF}$		-	3.4	7.5	1.0	9.0	14.4	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V; } C_L = 50 \text{ pF}$		-	4.5	9.5	1.0	11.5	14.4	ns
t _{dis}	disable time	nOE to nYn; see Figure 6	[2]							
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V; } C_L = 15 \text{ pF}$		-	3.9	6.1	1.0	6.7	8.3	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}; C_L = 50 \text{ pF}$		-	6.2	8.7	1.0	9.2	11.5	ns
C_{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}; C_L = 50 \text{ pF};$ $f_i = 1 \text{ MHz}$	<u>[3]</u>	-	9	-	-	-	-	pF

- [1] Typical values are measured at nominal supply voltage ($V_{CC} = 3.3 \text{ V}$ and $V_{CC} = 5.0 \text{ V}$).
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{en} is the same as t_{PZH} and t_{PZL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

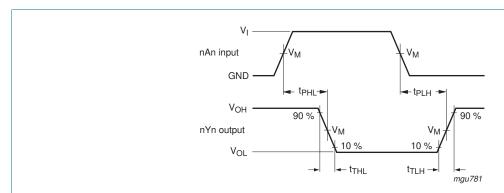
C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

11. Waveforms



Measurement points are given in Table 8.

 $\ensuremath{V_{\text{OL}}}$ and $\ensuremath{V_{\text{OH}}}$ are typical voltage output drop that occur with the output load.

Fig 5. Propagation delay input (nAn) to output (nYn)

74AHC_AHCT240

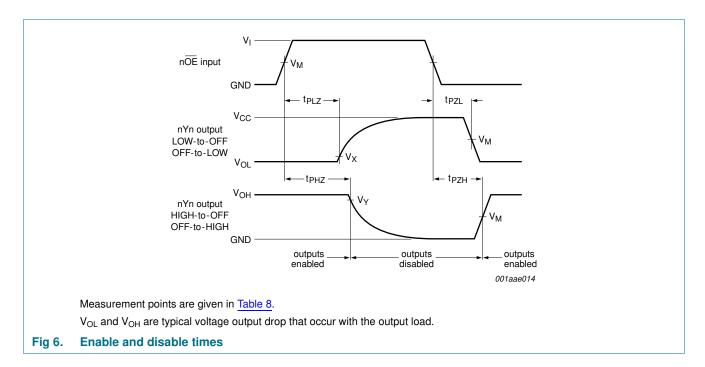
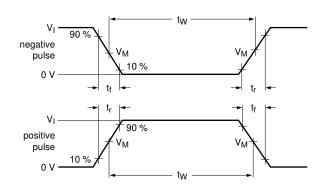
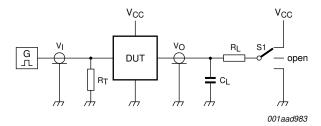


Table 8. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74AHC240	0.5V _{CC}	0.5V _{CC}	V _{OL} + 0.3 V	$V_{OH}-0.3\ V$
74AHCT240	1.5 V	0.5V _{CC}	V _{OL} + 0.3 V	V _{OH} – 0.3 V

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Test data is given in Table 9.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

R_L = Load resistance.

S1 = Test selection switch.

Fig 7. Load circuitry for switching times

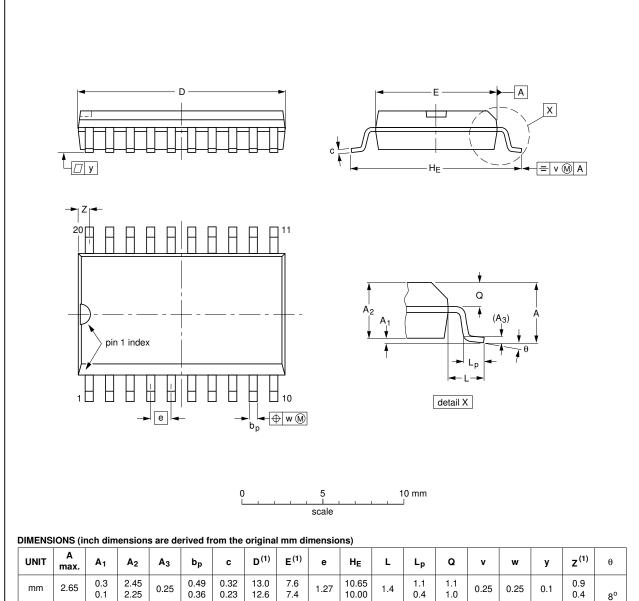
Table 9. Test data

Туре	Input		Load		S1 position	31 position			
	V _I	t _r , t _f	C _L	R _L	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}		
74AHC240	V_{CC}	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}		
74AHCT240	3.0 V	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}		

12. Package outline

SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



UNIT	A max.	A ₁	A ₂	А3	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.3 0.1	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.1	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.05	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013				99-12-27 03-02-19	

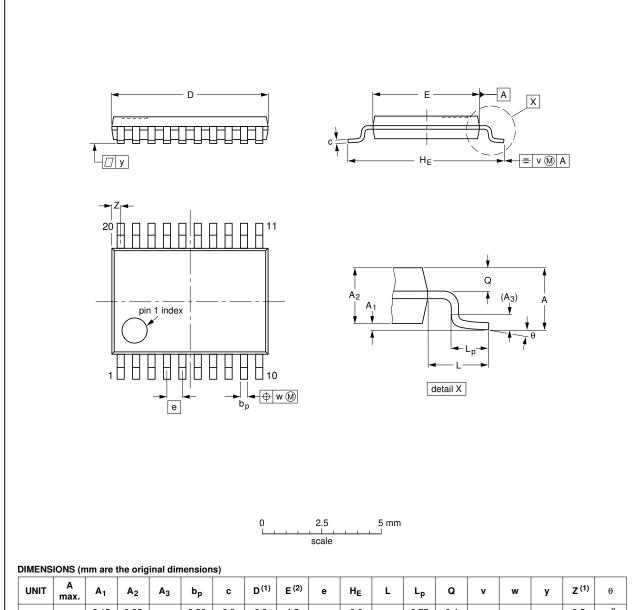
Package outline SOT163-1 (SO20)

74AHC_AHCT240

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ	
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°	

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT360-1		MO-153				-99-12-27 03-02-19	

Package outline SOT360-1 (TSSOP20)

74AHC_AHCT240

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DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

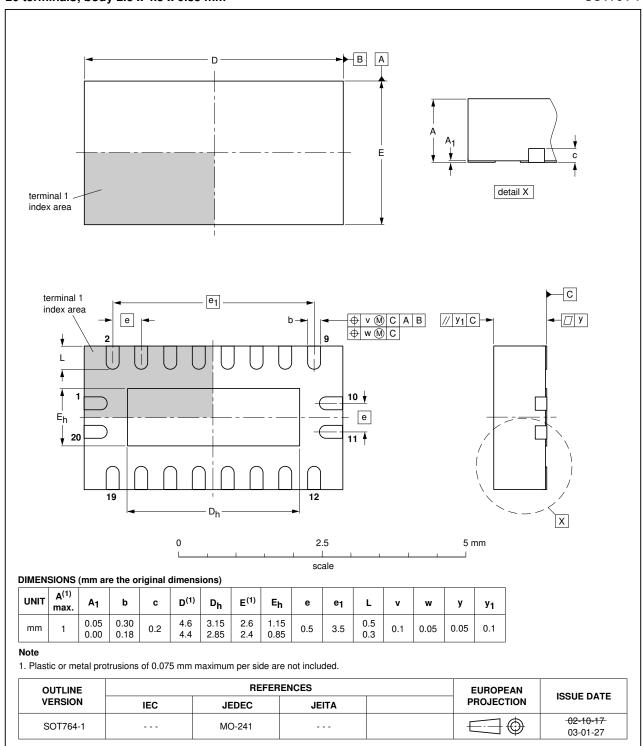


Fig 10. Package outline SOT764-1 (DHVQFN20)

74AHC_AHCT240

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CDM	Charge Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT240 v.4	20130925	Product data sheet	-	74AHC_AHCT240 v.3
Modifications:	 Figure 5 and 6 h 	ave been made visible (errata).	•	
74AHC_AHCT240 v.3	20111108	Product data sheet	-	74AHC_AHCT240 v.2
Modifications:	 Legal pages upd 	ated.		
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74AHC_AHCT240 v.1	20100111	Product data sheet	-	-

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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